
2SC3127, 2SC3128, 2SC3510

Silicon NPN Epitaxial

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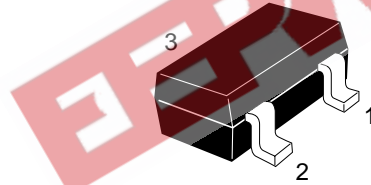
Application

UHF/VHF wide band amplifier

Outline

MPAK

2SC3127

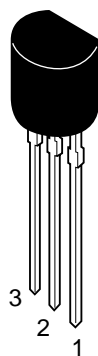


1. Emitter
2. Base
3. Collector

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TO-92 (2)

2SC3128, 2SC3510



1. Base
2. Emitter
3. Collector

Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	2SC3127*1	2SC3128	2SC3510	Unit
Collector to base voltage	V_{CBO}	20	20	20	V
Collector to emitter voltage	V_{CEO}	12	12	12	V
Emitter to base voltage	V_{EBO}	3	3	3	V
Collector current	I_C	50	50	50	mA
Collector power dissipation	P_C	150	350	600	mW
Junction temperature	T_j	150	150	150	°C
Storage temperature	T_{stg}	-55 to +150	-55 to +150	-55 to +150	°C

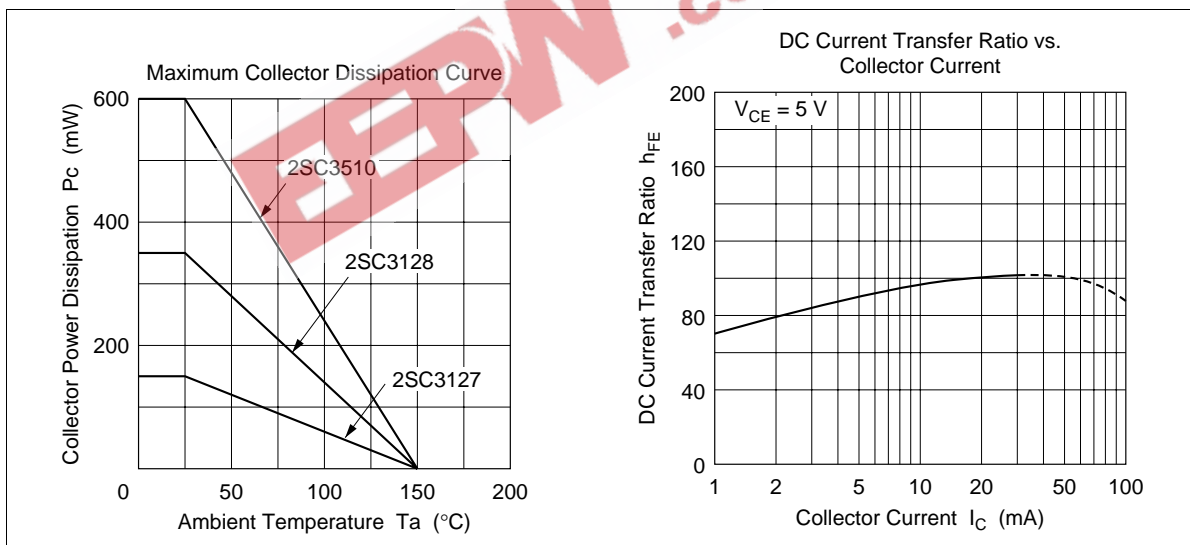
Note: 1. Marking for 2SC3127 is "ID-".

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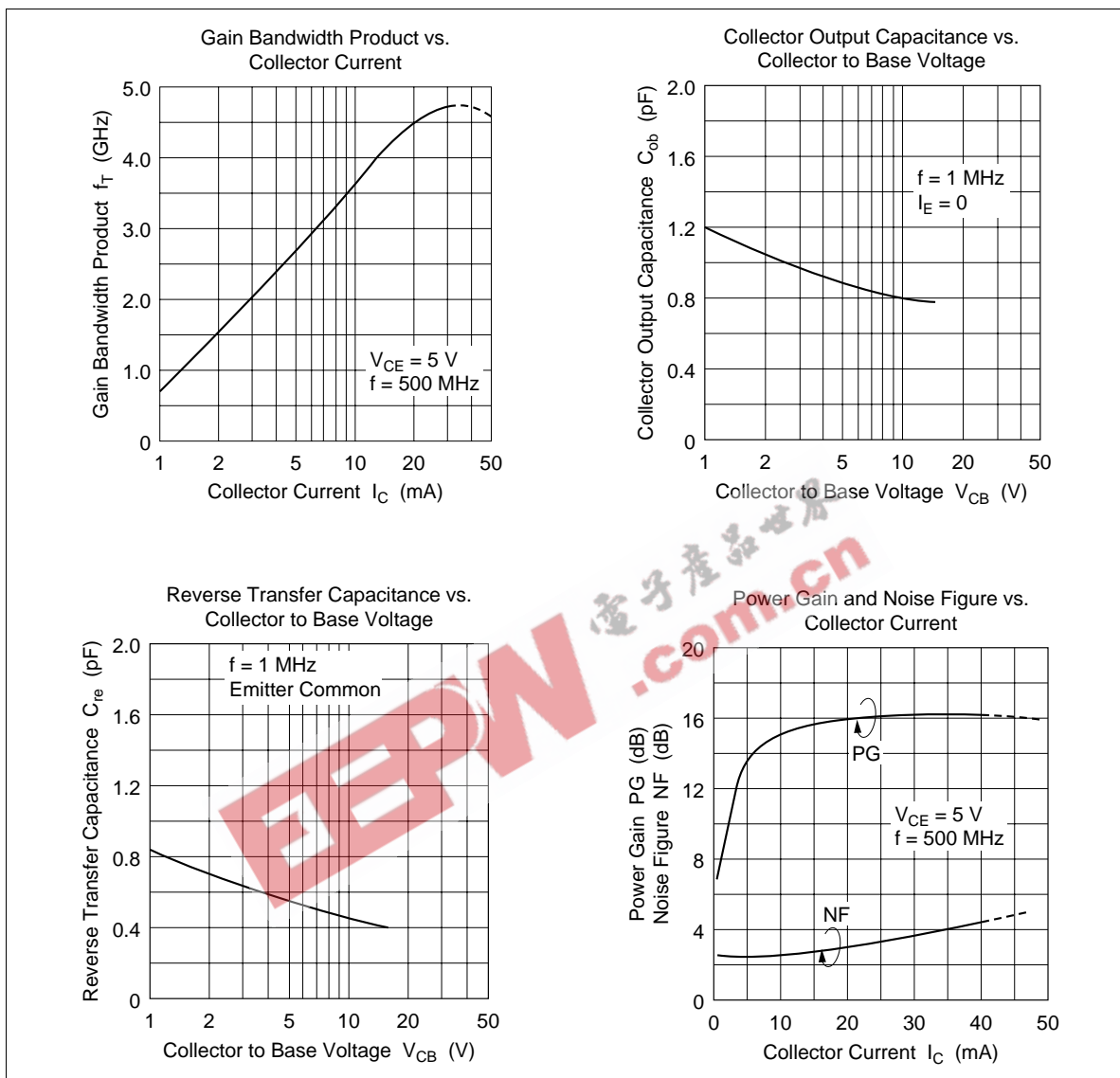
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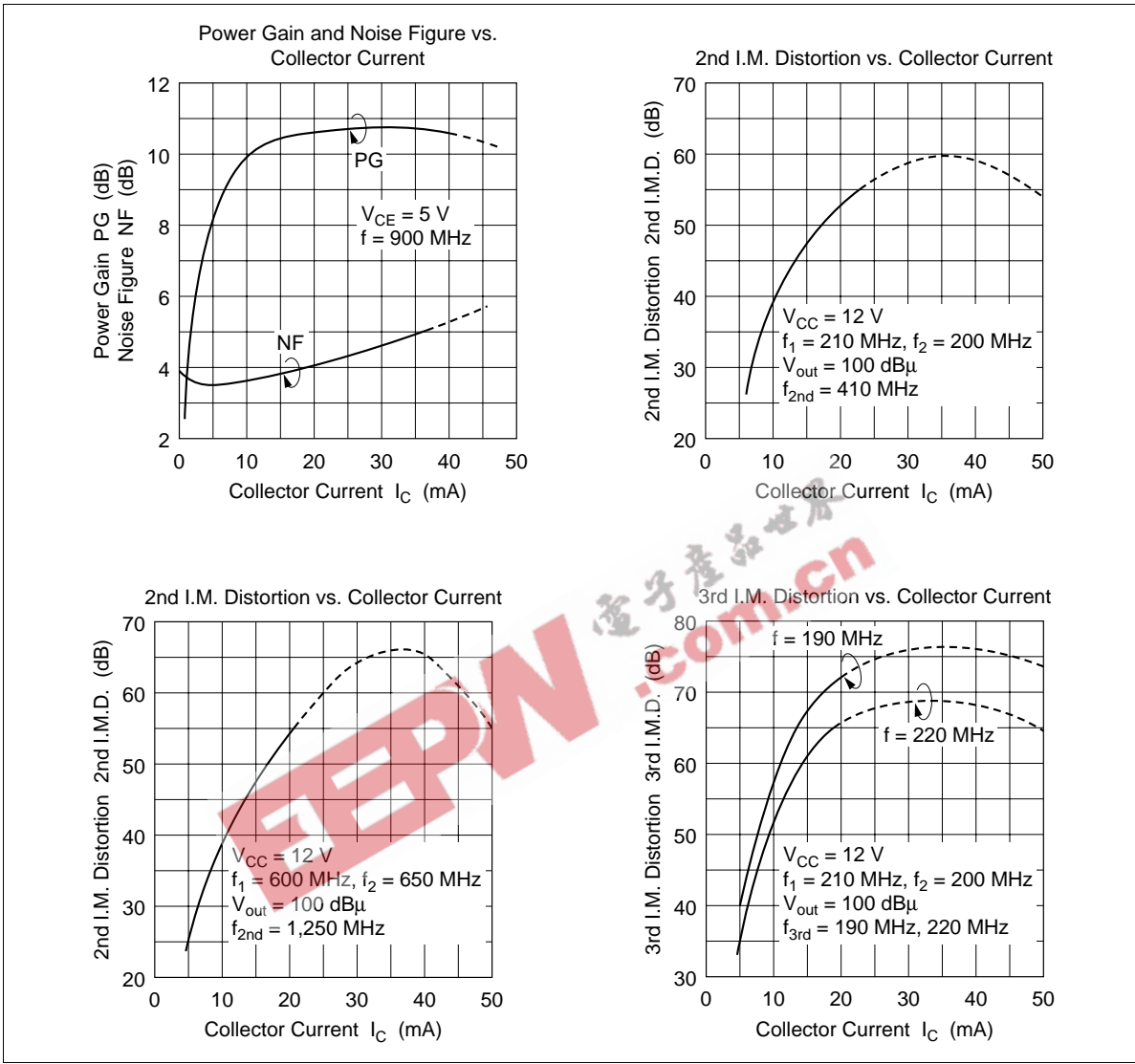
Electrical Characteristics (T_a = 25°C)

Item	Symbol	Min	Typ	Max	Unit	Test conditions
Collector to base breakdown voltage	$V_{(BR)CBO}$	20	—	—	V	$I_C = 10 \mu A, I_E = 0$
Collector to emitter breakdown voltage	$V_{(BR)CEO}$	12	—	—	V	$I_C = 1 \text{ mA}, R_{BE} = \infty$
Emitter cutoff current	I_{EBO}	—	—	10	μA	$V_{EB} = 3 \text{ V}, I_C = 0$
Collector cutoff current	I_{CBO}	—	—	0.5	μA	$V_{CB} = 12 \text{ V}, I_E = 0$
DC current transfer ratio	h_{FE}	30	90	200		$V_{CE} = 5 \text{ V}, I_C = 20 \text{ mA}$
Collector output capacitance	C_{ob}	—	0.9	1.5	pF	$V_{CB} = 5 \text{ V}, I_E = 0, f = 1 \text{ MHz}$
Gain bandwidth product	f_T	3.5	4.5	—	GHz	$V_{CE} = 5 \text{ V}, I_C = 20 \text{ mA}$
Power gain	PG	—	10.5	—	dB	$V_{CE} = 5 \text{ V}, I_C = 20 \text{ mA}, f = 900 \text{ MHz}$
Noise figure	NF	—	2.2	—	dB	$V_{CE} = 5 \text{ V}, I_C = 5 \text{ mA}, f = 900 \text{ MHz}$

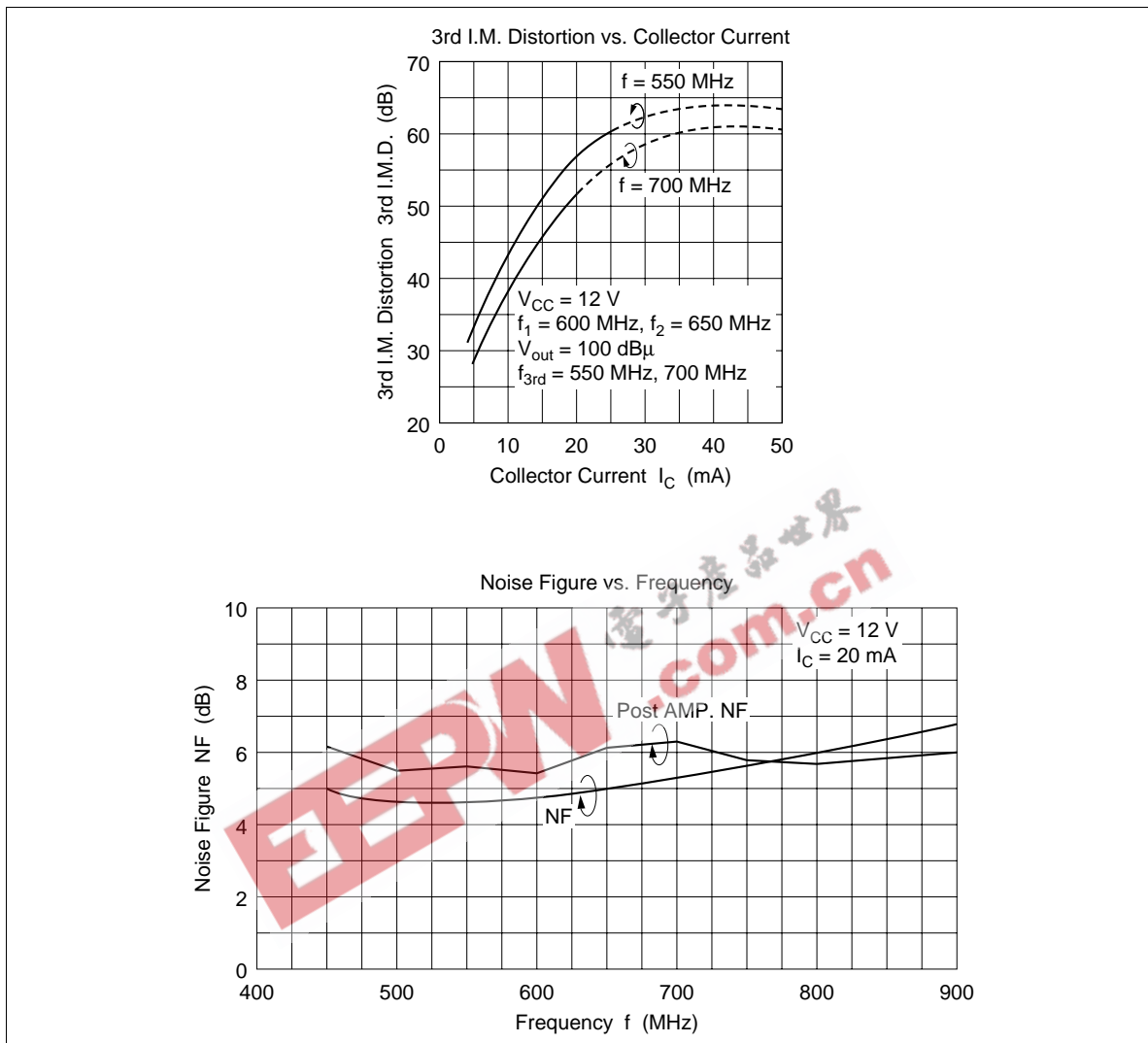


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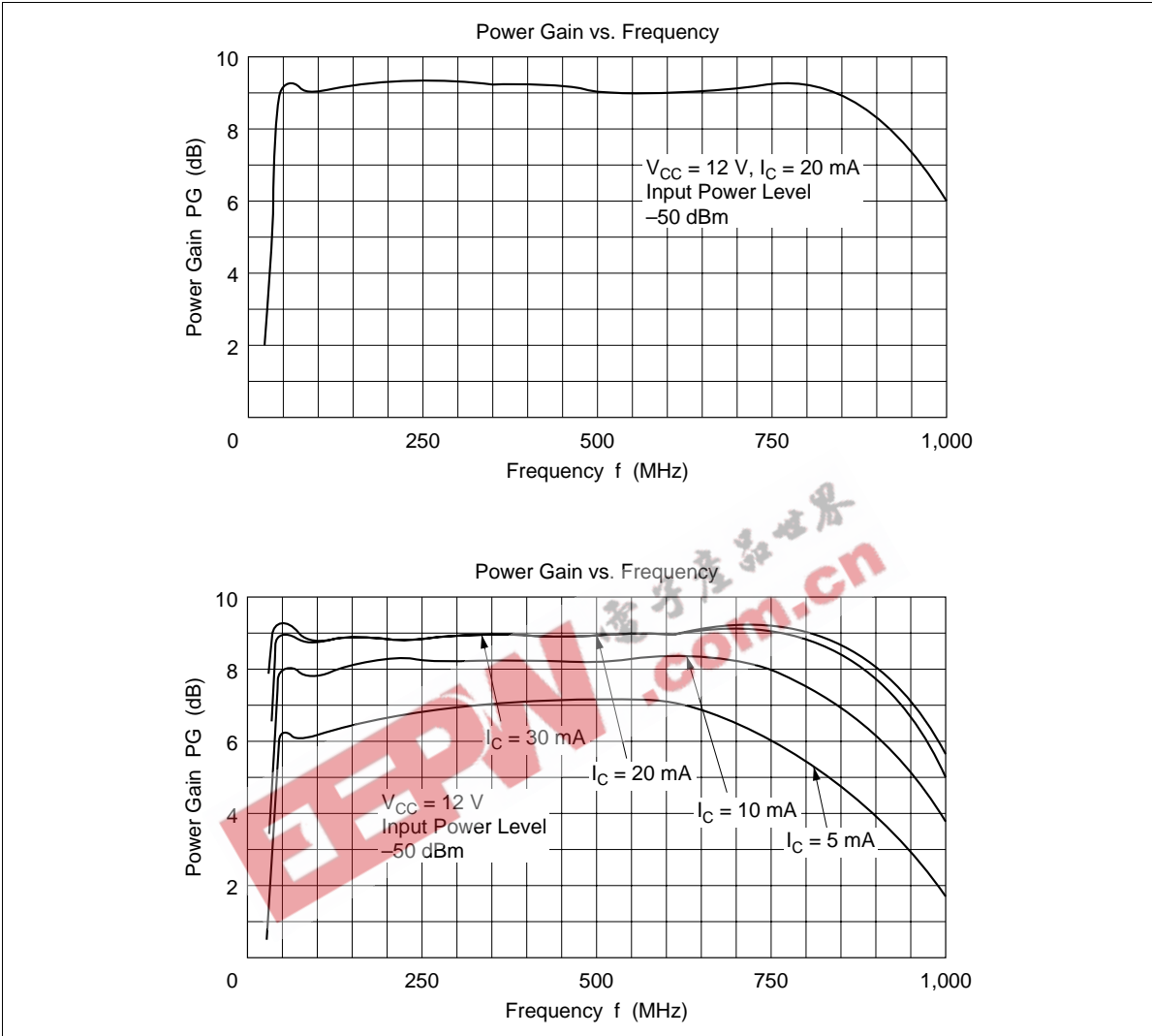




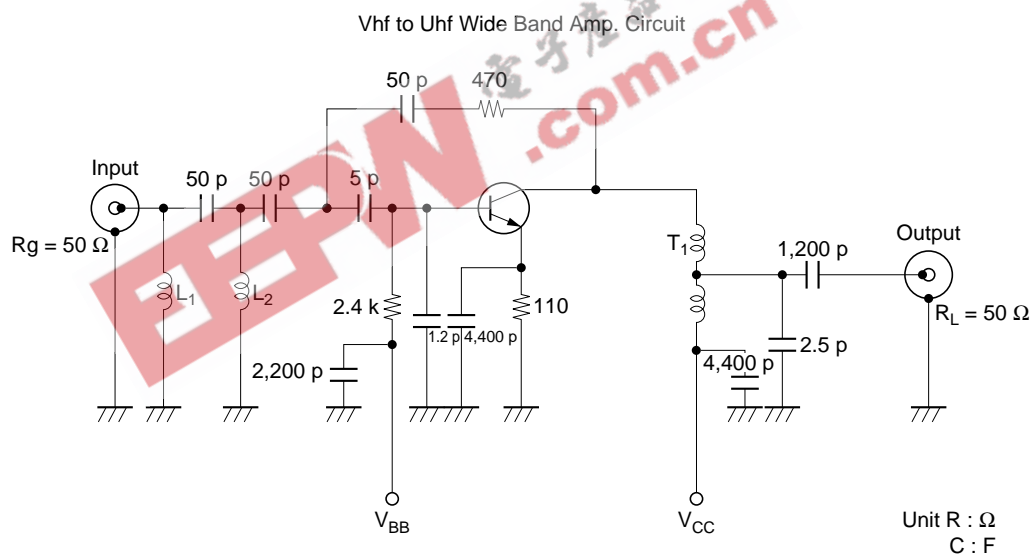
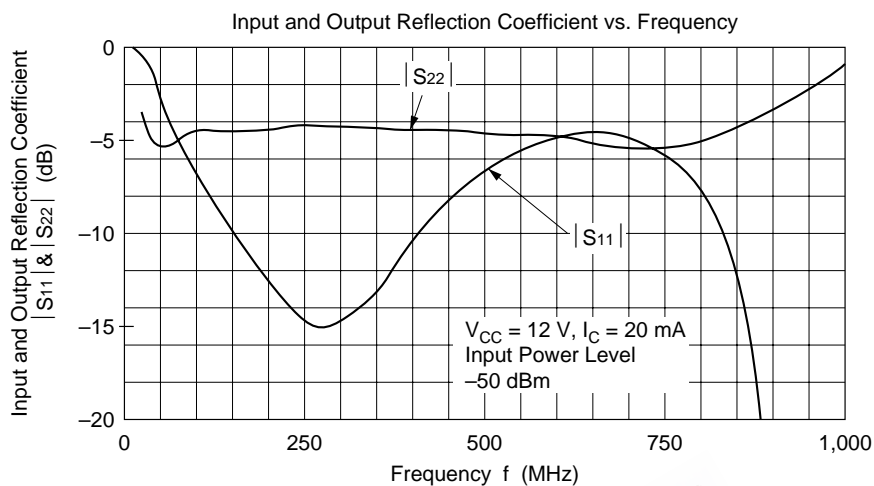
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Parts Specification

L_1 : Inside dia $\phi 3.0$ mm, $\phi 0.4$ mm Polyurethane Coated Copper wire 12 Turns.

L_2 : Inside dia $\phi 3.5$ mm, $\phi 0.5$ mm Polyurethane Coated Copper wire 9 Turns.

T_1 : Balance wind used Ferrite Core

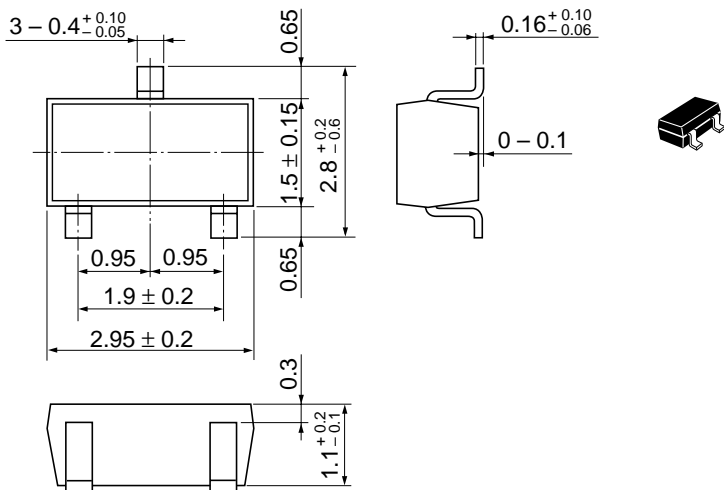
Outside dia $\phi 4.0$ mm, Inside dia $\phi 2.0$ mm

$\phi 0.1$ mm Polyurethane Coated Copper wire 3 Turns.

Ratio Input to Output is 2 : 1

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Unit: mm



Hitachi Code	MPAK
JEDEC	—
EIAJ	Conforms
Weight (reference value)	0.011 g

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